

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE6080AK uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

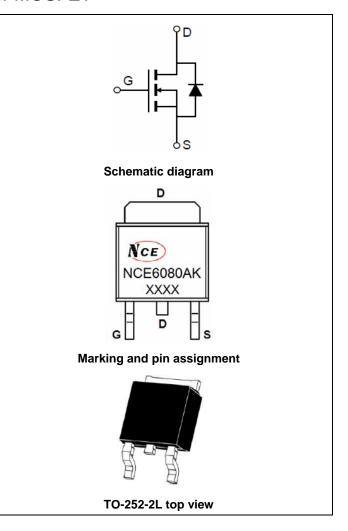
- V_{DS} =60V, I_D =80A $R_{DS(ON)}$ =6.5m Ω (typical) @ V_{GS} =10V $R_{DS(ON)}$ =7.5m Ω (typical) @ V_{GS} =4.5V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- PWM
- Load Switching

100% UIS TESTED!

100% ΔVds TESTED!



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE6080AK	NCE6080AK	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	80	Α
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	56.5	А
Pulsed Drain Current	I _{DM}	320	А
Maximum Power Dissipation	P _D	110	W
Derating factor		0.73	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	390	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}\!\mathbb{C}$



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Thermal Characteristic

Thermal Resistance, Junction-to-Case (Note 2)	R _{0JC}	1.36	°C/W
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	0.8	1.3	1.8	V
Drain-Source On-State Resistance	В	V _{GS} =10V, I _D =20A	-	6.5	8.0	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =20A	-	7.5	9.5	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =20A	-	20	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	// -20/// -0//	-	4000	-	PF
Output Capacitance	Coss	V_{DS} =30V, V_{GS} =0V, F=1.0MHz	-	290	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.UIVITZ	-	210	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	8.5	-	nS
Turn-on Rise Time	t _r	V_{DD} =30V, R_L =1 Ω	-	7	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =3 Ω	-	40	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Qg	V -20VI -20A	-	90.3		nC
Gate-Source Charge	Q_{gs}	V_{DS} =30V, I_{D} =20A, V_{GS} =10V	-	10.9		nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	20.6		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	80	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 20A	-	32	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	45	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

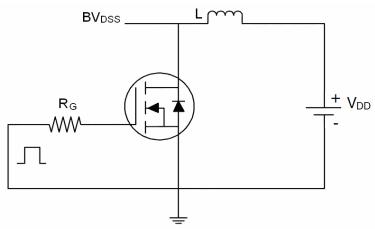
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. E_{AS} condition : $Tj{=}25\,^{\circ}\!\mathrm{C}$, $V_{DD}{=}30V$, $V_{G}{=}10V$, $L{=}0.5mH$, $Rg{=}25\Omega$

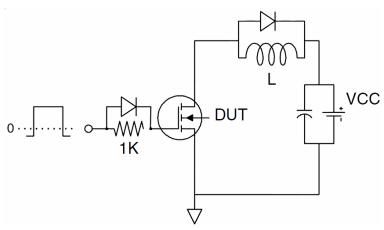


Test circuit

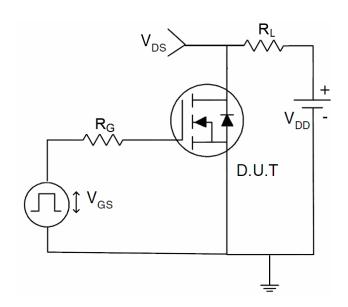
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit



Typical Electrical and Thermal Characteristics (Curves)

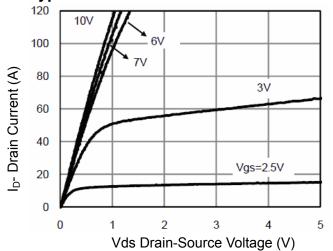


Figure 1 Output Characteristics

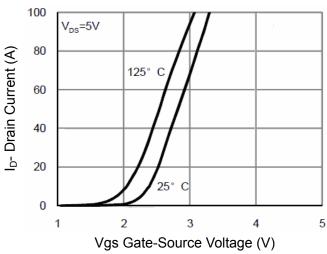


Figure 2 Transfer Characteristics

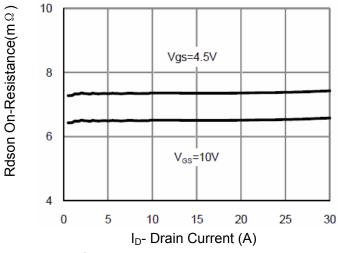


Figure 3 Rdson- Drain Current

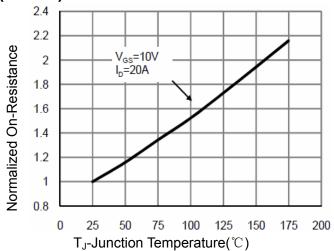


Figure 4 Rdson-JunctionTemperature

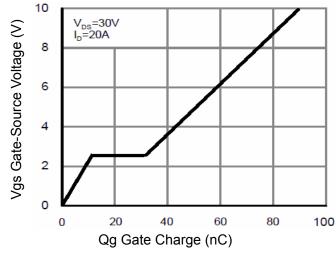


Figure 5 Gate Charge

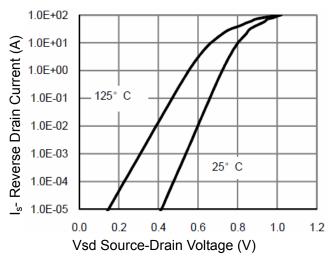
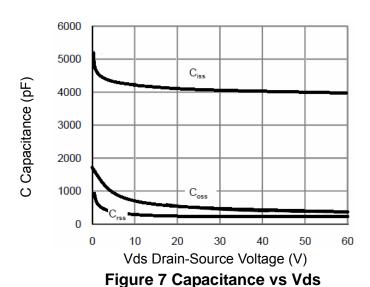
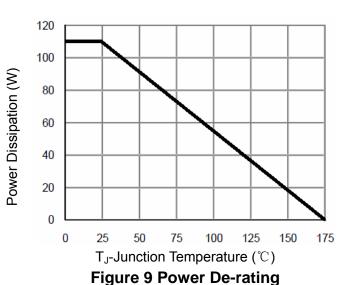


Figure 6 Source- Drain Diode Forward





1000.0 10µs 100.0 R_{DS(ON)} limited lp- Drain Current (A) 10.0 DC 1.0 T_{J(Max)}=175° C T_c=25° C 0.1 0.0 0.01 0.1 10 100 1000 Vds Drain-Source Voltage (V)

80

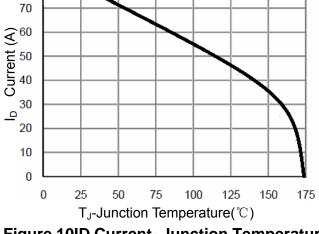
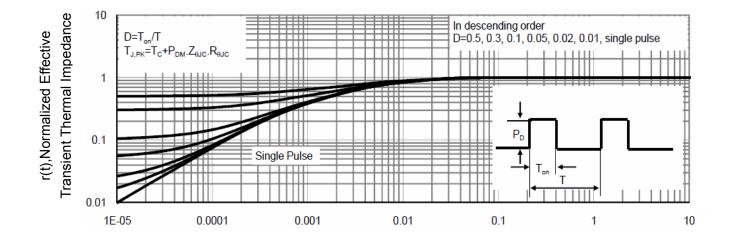


Figure 8 Safe Operation Area

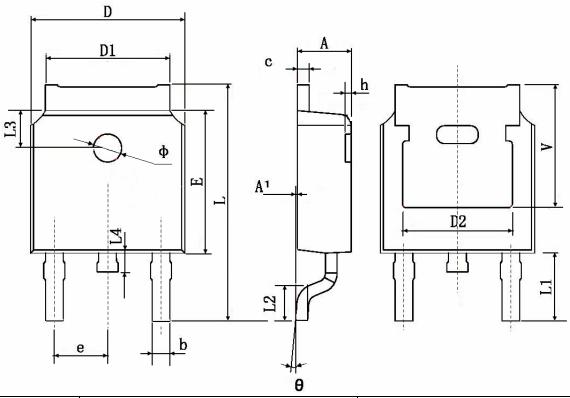
Figure 10ID Current- Junction Temperature



Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance



TO-252 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483	3 TYP.	0.190 TYP.		
Е	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	O TYP.	0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600	1.600 TYP.		TYP.	
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	TYP.	0.211 TYP.		



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